NSN 5961-01-449-1357

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-449-1357 **Inclosure Material:** Glass **Overall Length:** Between 0.160 inches and 0.220 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.100 inches and 0.170 inches **End Application:** 2350-01-328-5964 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 2000.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 25.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-prf-19500/576 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.